

W7676CSYC04

SUPER BRIGHT YELLOW

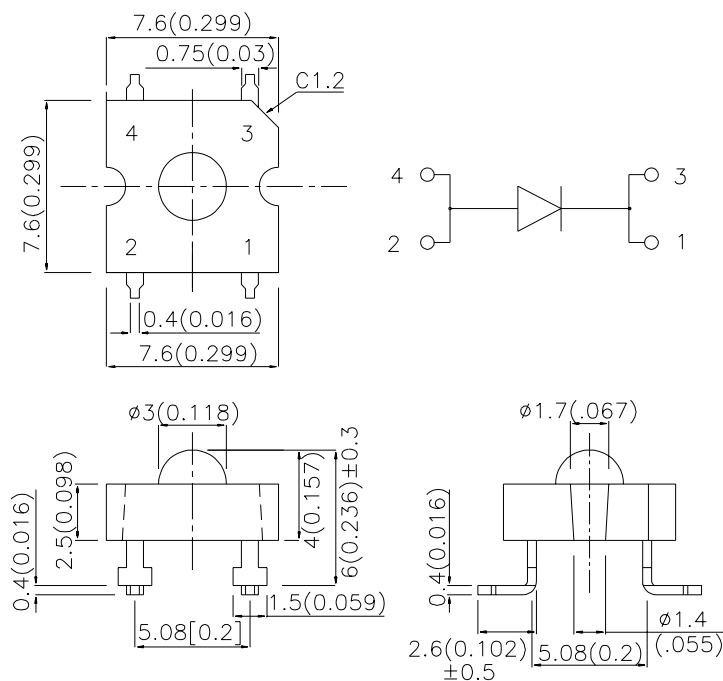
Features

- SUPER FLUX OUTPUT.
- DESIGN FOR HIGH CURRENT OPERATION.
- OUTSTANDING MATERIAL EFFICIENCY.
- RELIABLE AND RUGGED.

Description

The Super Bright Yellow source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20 mA *70mA		Viewing Angle
			Min.	Typ.	2θ1/2
W7676CSYC04	SUPER BRIGHT YELLOW (InGaAlP)	WATER CLEAR	180	400	70°
			*280	*700	70°

Notes:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
2. * Luminous intensity with asterisk is measured at 70mA.
3. Drive current between 10mA and 30mA are recommended for long term performance.
4. Operation at current below 10mA is not recommended.

Electrical / Optical Characteristics at T_A=25°C

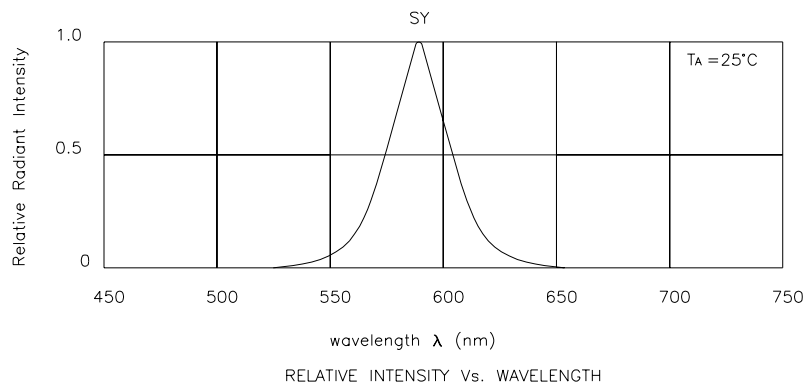
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	Super Bright Yellow	590		nm	I _F =20mA
λ _D	Dominate Wavelength	Super Bright Yellow	588		nm	I _F =20mA
Δλ _{1/2}	Spectral Line Half-width	Super Bright Yellow	28		nm	I _F =20mA
C	Capacitance	Super Bright Yellow	25		pF	V _F =0V; f=1MHz
V _F	Forward Voltage	Super Bright Yellow	2.0	2.5	V	I _F =20mA
I _R	Reverse Current	Super Bright Yellow		10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	Super Bright Yellow	Units
Power dissipation	125	mW
DC Forward Current	30	mA
Peak Forward Current [1]	150	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



Super Bright Yellow

W7676CSYC04

